

October 1987 Revised January 1999

# CD4001BC/CD4011BC Quad 2-Input NOR Buffered B Series Gate • Quad 2-Input NAND Buffered B Series Gate

#### **General Description**

The CD4001BC and CD4011BC quad gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain.

All inputs are protected against static discharge with diodes to  $\rm V_{DD}$  and  $\rm V_{SS}.$ 

#### **Features**

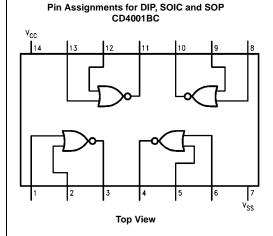
- Low power TTL:
  - Fan out of 2 driving 74L compatibility: or 1 driving 74LS
- 5V-10V-15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 µA at 15V over full temperature range

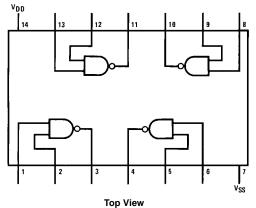
#### **Ordering Code:**

Order Number	Package Number	Package Description				
CD4001BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow				
CD4001BCSJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide				
CD4001BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide				
CD4011BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-120, 0.150" Narrow				
CD4011BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide				

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

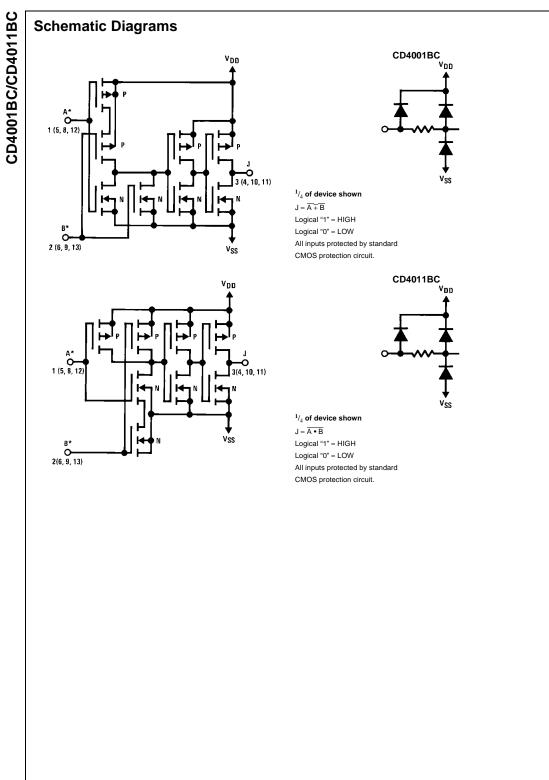
#### **Connection Diagrams**





Pin Assignments for DIP and SOIC

CD4011BC



#### **Absolute Maximum Ratings**(Note 1)

(Note 2)

Voltage at any Pin -0.5V to  $V_{DD}$  +0.5V

Power Dissipation (P<sub>D</sub>)

Dual-In-Line 700 mW Small Outline 500 mW V<sub>DD</sub> Range  $-0.5 V_{DC}$  to +18  $V_{DC}$ 

Storage Temperature (T<sub>S</sub>) -65°C to +150°C

Lead Temperature (T<sub>L</sub>)

260°C (Soldering, 10 seconds)

#### **Recommended Operating Conditions**

3  $V_{DC}$  to 15  $V_{DC}$ Operating Range (V<sub>DD</sub>)

Operating Temperature Range

CD4001BC, CD4011BC -40°C to +85°C

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics tables provide conditions

Note 2: All voltages measured with respect to  $\mathbf{V}_{\text{SS}}$  unless otherwise speci-

#### DC Electrical Characteristics (Note 2)

Symbol	Parameter	Conditions	-40°C		+25°C			+85°C		Units
		Conditions	Min	Max	Min	Тур	Max	Min	Max	Ollits
I <sub>DD</sub>	Quiescent Device	$V_{DD} = 5V$ , $V_{IN} = V_{DD}$ or $V_{SS}$		1		0.004	1		7.5	μΑ
	Current	$V_{DD} = 10V$ , $V_{IN} = V_{DD}$ or $V_{SS}$		2		0.005	2		15	μΑ
		$V_{DD} = 15V$ , $V_{IN} = V_{DD}$ or $V_{SS}$		4		0.006	4		30	μΑ
V <sub>OL</sub>	LOW Level	$V_{DD} = 5V$		0.05		0	0.05		0.05	V
	Output Voltage	$V_{DD} = 10V$ $ I_O  < 1 \mu A$		0.05		0	0.05		0.05	V
		V <sub>DD</sub> = 15V		0.05		0	0.05		0.05	V
V <sub>OH</sub>	HIGH Level	$V_{DD} = 5V$	4.95		4.95	5		4.95		V
	Output Voltage	$V_{DD} = 10V$ $ I_O  < 1 \mu A$	9.95		9.95	10		9.95		V
		V <sub>DD</sub> = 15V	14.95		14.95	15		14.95		V
V <sub>IL</sub>	LOW Level	$V_{DD} = 5V, V_{O} = 4.5V$		1.5		2	1.5		1.5	V
	Input Voltage	$V_{DD} = 10V, V_{O} = 9.0V$		3.0		4	3.0		3.0	V
		$V_{DD} = 15V, V_{O} = 13.5V$		4.0		6	4.0		4.0	V
V <sub>IH</sub>	HIGH Level	$V_{DD} = 5V, V_{O} = 0.5V$	3.5		3.5	3		3.5		V
	Input Voltage	$V_{DD} = 10V, V_{O} = 1.0V$	7.0		7.0	6		7.0		V
		$V_{DD} = 15V, V_{O} = 1.5V$	11.0		11.0	9		11.0		V
I <sub>OL</sub>	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.52		0.44	0.88		0.36		mA
	Current	$V_{DD} = 10V, V_{O} = 0.5V$	1.3		1.1	2.25		0.9		mA
	(Note 3)	$V_{DD} = 15V, V_{O} = 1.5V$	3.6		3.0	8.8		2.4		mA
I <sub>OH</sub>	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.52		-0.44	-0.88		-0.36		mA
	Current	$V_{DD} = 10V, V_{O} = 9.5V$	-1.3		-1.1	-2.25		-0.9		mA
	(Note 3)	$V_{DD} = 15V, V_{O} = 13.5V$	-3.6		-3.0	-8.8		-2.4		mA
I <sub>IN</sub>	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.30		-10 <sup>-5</sup>	-0.30		-1.0	μΑ
		$V_{DD} = 15V, V_{IN} = 15V$		0.30		10 <sup>-5</sup>	0.30		1.0	μΑ

Note 3: I<sub>OL</sub> and I<sub>OH</sub> are tested one output at a time.

#### **AC Electrical Characteristics** (Note 4)

CD4001BC:  $T_A = 25^{\circ}C$ , Input  $t_r$ :  $t_r = 20$  ns.  $C_L = 50$  pF,  $R_L = 200k$ . Typical temperature coefficient is  $0.3\%/^{\circ}C$ .

Symbol	Parameter	Conditions	Тур	Max	Units
t <sub>PHL</sub>	Propagation Delay Time,	$V_{DD} = 5V$	120	250	ns
	HIGH-to-LOW Level	V <sub>DD</sub> = 10V	50	100	ns
		V <sub>DD</sub> = 15V	35	70	ns
t <sub>PLH</sub>	Propagation Delay Time,	$V_{DD} = 5V$	110	250	ns
	LOW-to-HIGH Level	V <sub>DD</sub> = 10V	50	100	ns
		V <sub>DD</sub> = 15V	35	70	ns
t <sub>THL</sub> , t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$	90	200	ns
		V <sub>DD</sub> = 10V	50	100	ns
		V <sub>DD</sub> = 15V	40	80	ns
C <sub>IN</sub>	Average Input Capacitance	Any Input	5	7.5	pF
C <sub>PD</sub>	Power Dissipation Capacity	Any Gate	14		pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

#### AC Electrical Characteristics (Note 5)

CD4011BC:  $T_A$ = 25°C, Input  $t_r$ :  $t_f$  = 20 ns.  $C_L$  = 50 pF,  $R_L$  = 200k. Typical Temperature Coefficient is 0.3%/°C.

Symbol	Parameter	Conditions	Тур	Max	Units
t <sub>PHL</sub>	Propagation Delay,	$V_{DD} = 5V$	120	250	ns
	HIGH-to-LOW Level	$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	35	70	ns
t <sub>PLH</sub>	Propagation Delay,	$V_{DD} = 5V$	85	250	ns
	LOW-to-HIGH Level	$V_{DD} = 10V$	40	100	ns
		$V_{DD} = 15V$	30	70	ns
t <sub>THL</sub> , t <sub>TLH</sub>	Transition Time	$V_{DD} = 5V$	90	200	ns
		$V_{DD} = 10V$	50	100	ns
		$V_{DD} = 15V$	40	80	ns
C <sub>IN</sub>	Average Input Capacitance	Any Input	5	7.5	pF
C <sub>PD</sub>	Power Dissipation Capacity	Any Gate	14		pF

Note 5: AC Parameters are guaranteed by DC correlated testing.

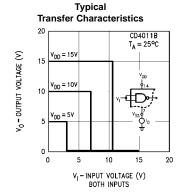
#### **Typical Performance Characteristics**

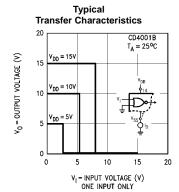
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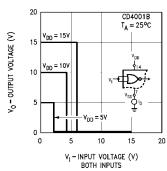
Transfer Characteristics

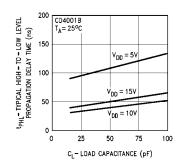
20  $V_{DD} = 15V$   $V_{DD} = 15V$   $V_{DD} = 10V$   $V_{DD} = 5V$   $V_{DD} = 5V$   $V_{DD} = 10V$   $V_{DD} = 10V$ 

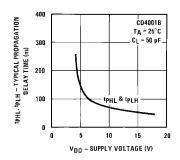


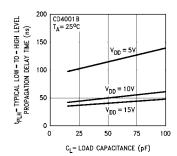


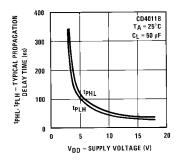
### **Typical Transfer Characteristics**

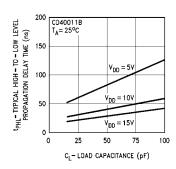


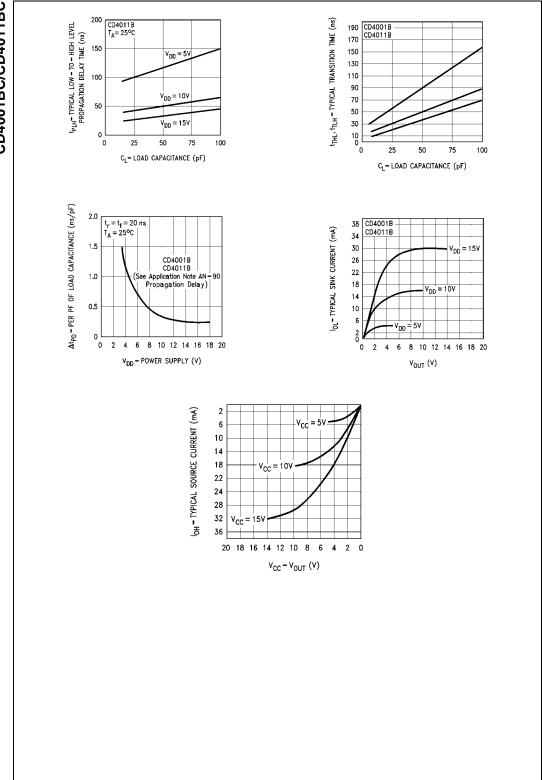


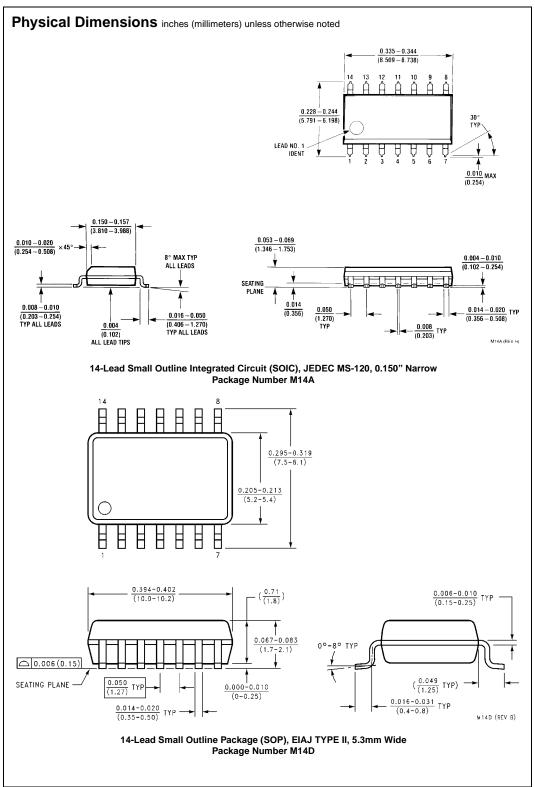




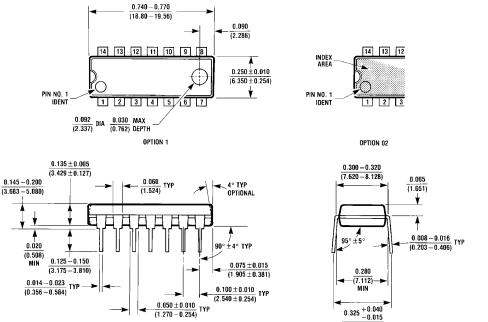








#### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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N14A (REV.F)

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